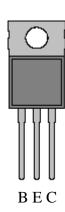
2SC1590 Silicon NPN Transistor RF Power Output

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The 2SC1590 is a silicon NPN epitaxial planer type transistor designed for 136-174MHz RF power amplifiers on VHF band mobile radio applications.



Features:

- High Power Gain: $G_{pe} > = 10dB (V_{CC} = 13.5V, P_O = 6W, f = 175MHz)$
- Ability to Withstand more than 20:1 VSWR Load when Operated at: $V_{CC} = 15.2V, P_O = 6W, f = 175MHz$

Application:

• 4 to 5 Watt Output Power Amplifier Applications in VHF Band

Absolute Maximum Ratings: $(T_C = +25^{\circ}C \text{ unless otherwise specified})$

| Collector-Emitter Voltage ($R_{BE} = Infinity$), V_{CEO} | 17V |
|--|-----------------------------------|
| Collector-Base Voltage, V _{CBO} | 35V |
| Emitter-Base Voltage, V _{EBO} | 4V |
| Collector Current, I _C | 12A |
| Collector Power Dissipation ($T_A = +25^{\circ}C$), P_D | 1.5W |
| Collector Power Dissipation ($T_C = +50^{\circ}C$), P_D | 12.5W |
| Operating Junction Temperature, T _J | +150°C |
| Storage Temperature Range, T _{stg} | -55° to $+150^{\circ}$ C |
| Thermal Resistance, Junction-to-Case, R _{thJC} | 10°C/W |
| Thermal Resistance, Junction-to-Ambient, R _{thJA} | 83°C/W |

Electrical Characteristics: (T_C = +25°C unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|--|----------------------|---------------------------------------|-----|-----|-----|------|
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | $I_C = 10 \text{mA}, I_E = 0$ | 35 | - | - | V |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | $I_C = 50 mA$, $R_{BE} = Infinity$ | 17 | - | - | V |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | $I_{\rm E}=5{\rm mA},\ I_{\rm C}=0$ | 4 | - | - | V |
| Collector Cutoff Current | I _{CBO} | $V_{CB} = 25V I_E = 0$ | - | - | 500 | μΑ |
| Emitter Cutoff Current | I _{EBO} | $V_{EB} = 3V, I_C = 0$ | - | - | 500 | μΑ |
| DC Forward Current Gain | h _{FE} | $V_{CE} = 10V, I_{C} = 100mA, Note 1$ | 10 | 50 | 180 | |
| Power Output | Po | $V_{CC} = 13.5V, P_{in} = 600mW, f =$ | 6 | 7 | - | W |
| Collector Efficiency | | 175MHz | 60 | 70 | - | % |

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